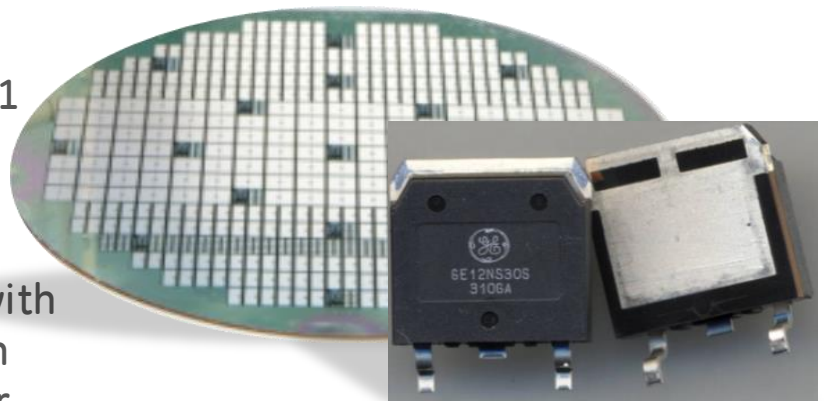


GE Silicon Carbide Power Conversion

GE Silicon Carbide (SiC) 1200V MOSFETs are qualified to AEC-Q101 and ready for your most demanding applications.

The combination of GE SiC devices with GE's application know-how results in astonishing improvements for power converters in high temperature operation, power density and efficiency. Size and weight savings of 2x over state of the art silicon have been demonstrated.



GE SiC wafer and packaged MOSFETs

GE leads the way with more than 50 years as an aerospace electrical power provider and a reputation for advanced, robust products. GE supplies a wide array of aerospace power conversion, distribution, generation and controls in use on military ground and air vehicles.

